

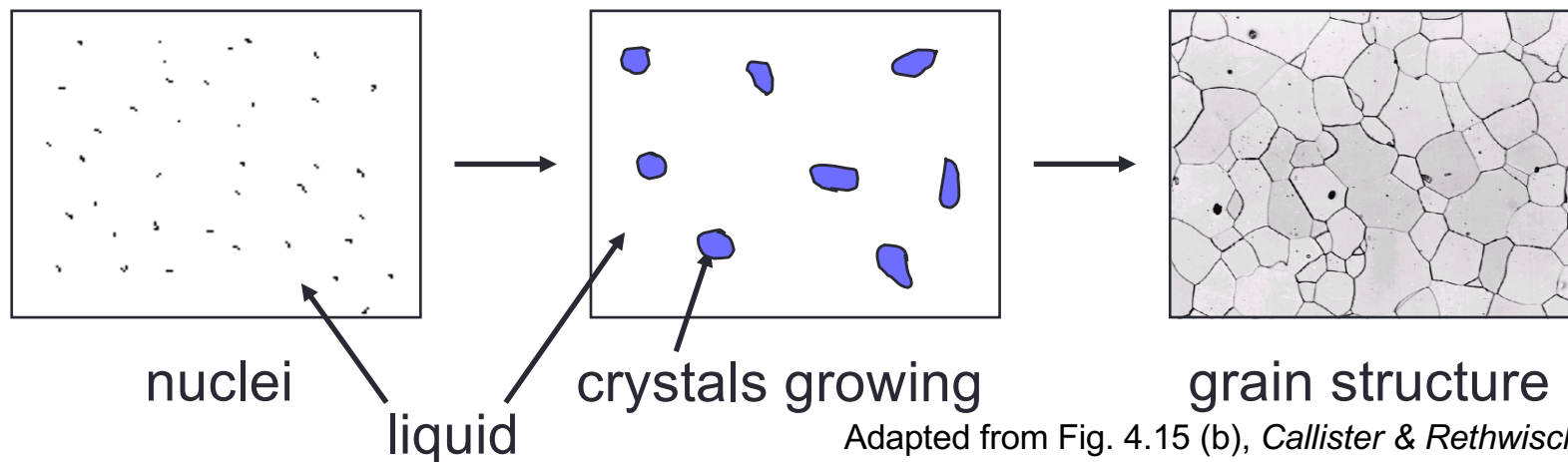
Chapter 4: Imperfections in Solids

ISSUES TO ADDRESS...

- What are the solidification mechanisms?
- What types of defects arise in solids?
- Can the number and type of defects be varied and controlled?
- How do defects affect material properties?
- Are defects undesirable?

Imperfections in Solids

- **Solidification** - result of casting of molten material
 - 2 steps
 - Nuclei form
 - Nuclei grow to form crystals – grain structure
- Start with a molten material – all liquid

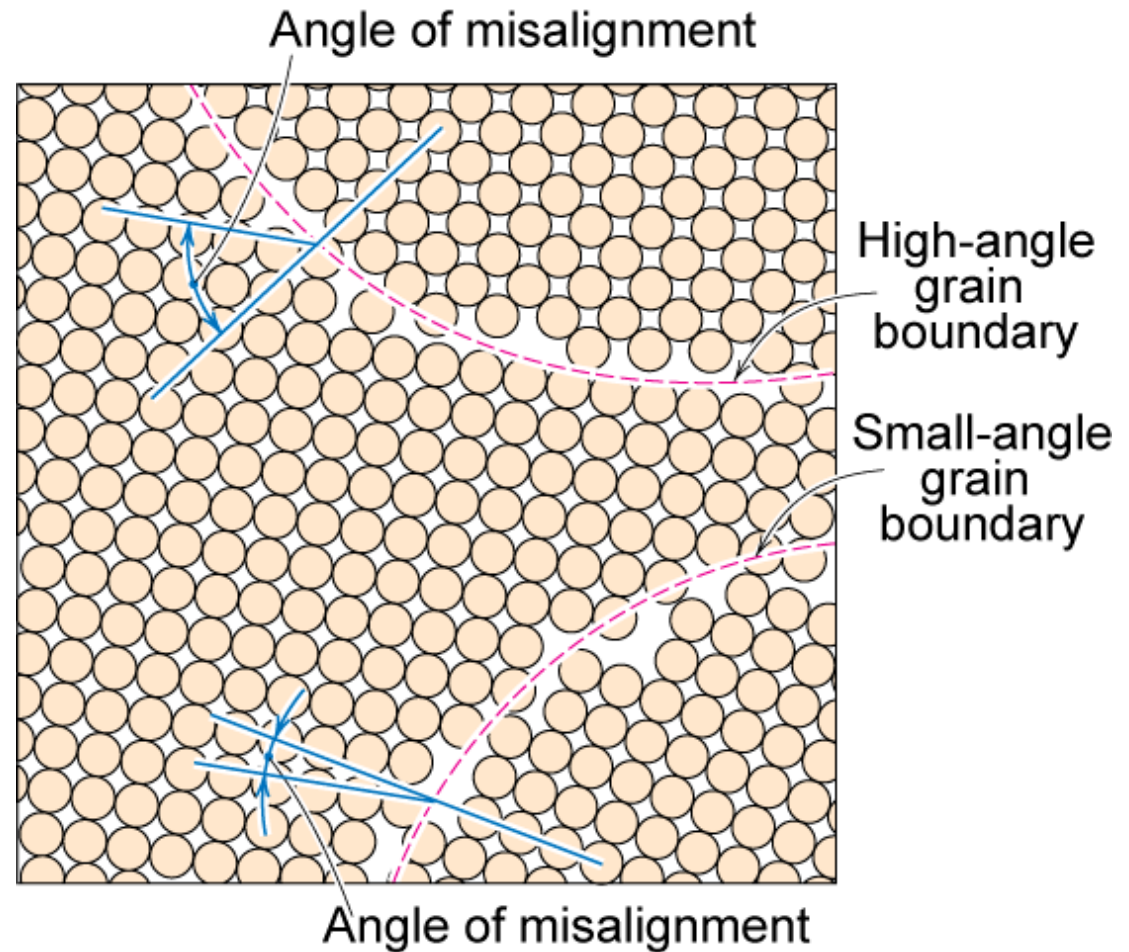


- Crystals grow until they meet each other

Polycrystalline Materials

Grain Boundaries

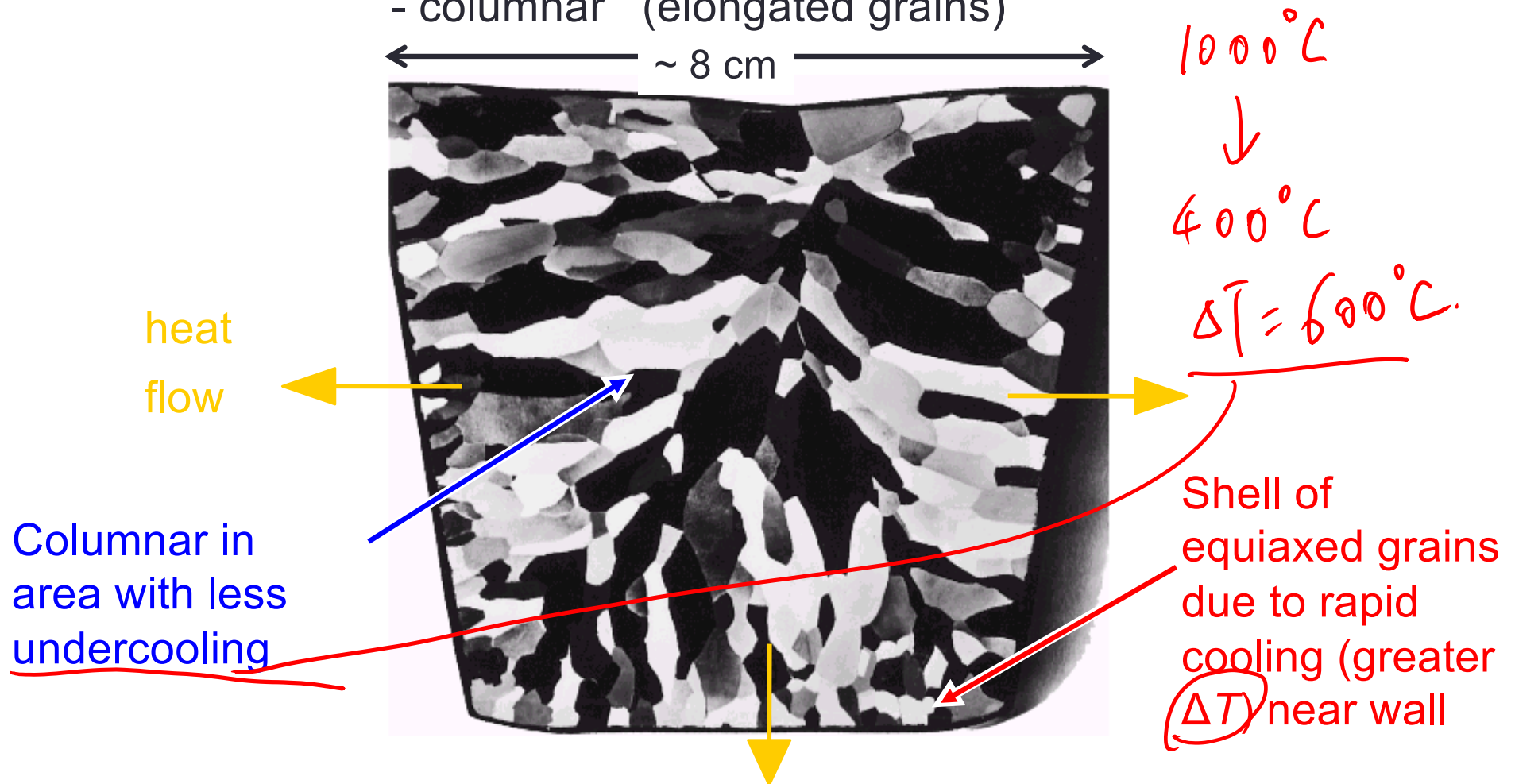
- regions between crystals
- transition from lattice of one region to that of the other
- slightly disordered
- low density in grain boundaries
 - high mobility
 - high diffusivity
 - high chemical reactivity



Adapted from Fig. 4.8,
Callister & Rethwisch 9e.

Solidification

- Grains can be
- equiaxed (roughly same size in all directions)
 - columnar (elongated grains)



Grain Refiner - added to make smaller, more uniform, equiaxed grains.

Imperfections in Solids

There is no such thing as a perfect crystal.

- What are these imperfections?
- Why are they important?

Many of the important properties of materials are due to the presence of imperfections.

Types of Imperfections

- Vacancy atoms
- Interstitial atoms
- Substitutional atoms

Point defects

- Dislocations

Line/linear defects

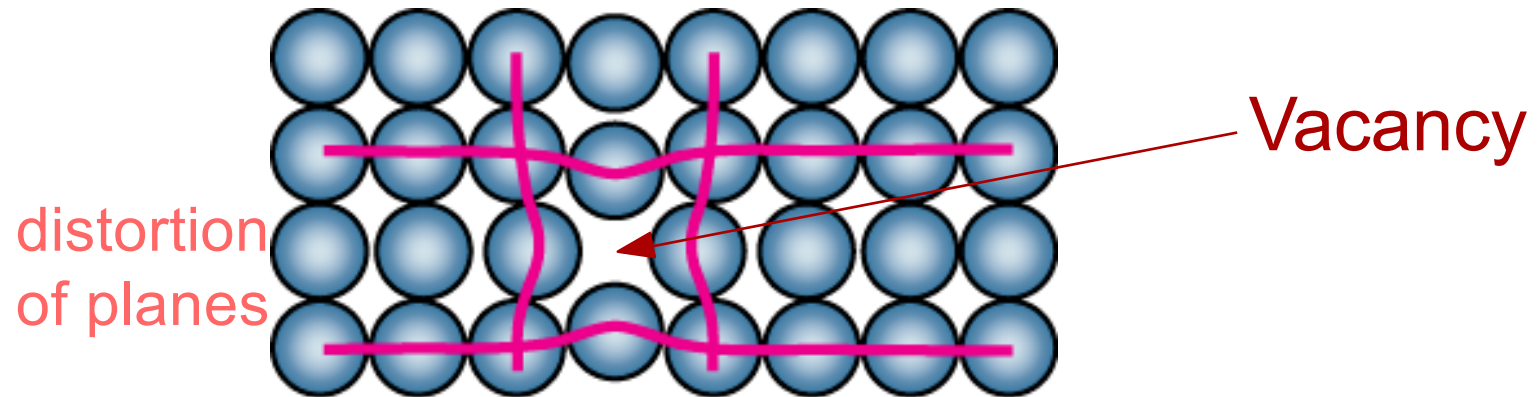
- Grain Boundaries

Area/planar defects

Point Defects in Metals

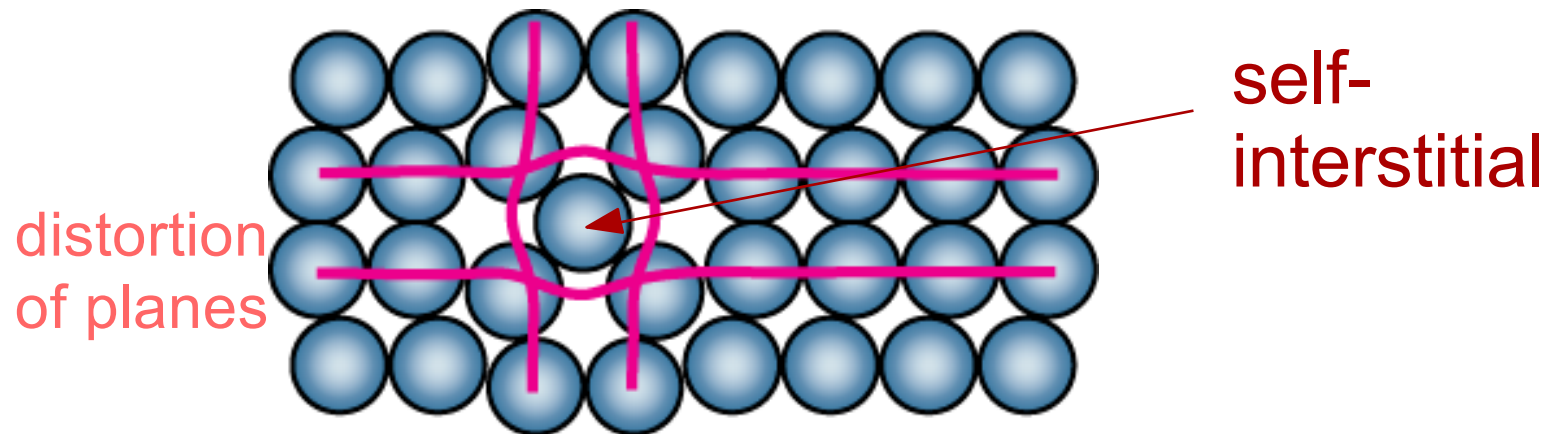
- **Vacancies:**

- vacant atomic sites in a structure.



- **Self-Interstitials:**

- "extra" atoms positioned between atomic sites.



Equilibrium Concentration: Point Defects

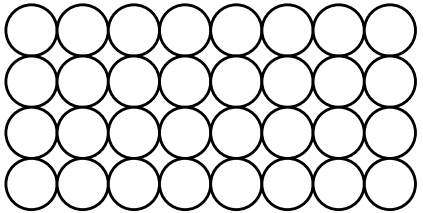
- Equilibrium concentration varies with temperature!

No. of defects $\rightarrow N_v$
 No. of potential defect sites $\rightarrow N$

$$\frac{N_v}{N} = \exp \left(\frac{-Q_v}{kT} \right)$$

Activation energy $\rightarrow Q_v$
 Boltzmann's constant $\rightarrow k$
 Temperature $\rightarrow T$

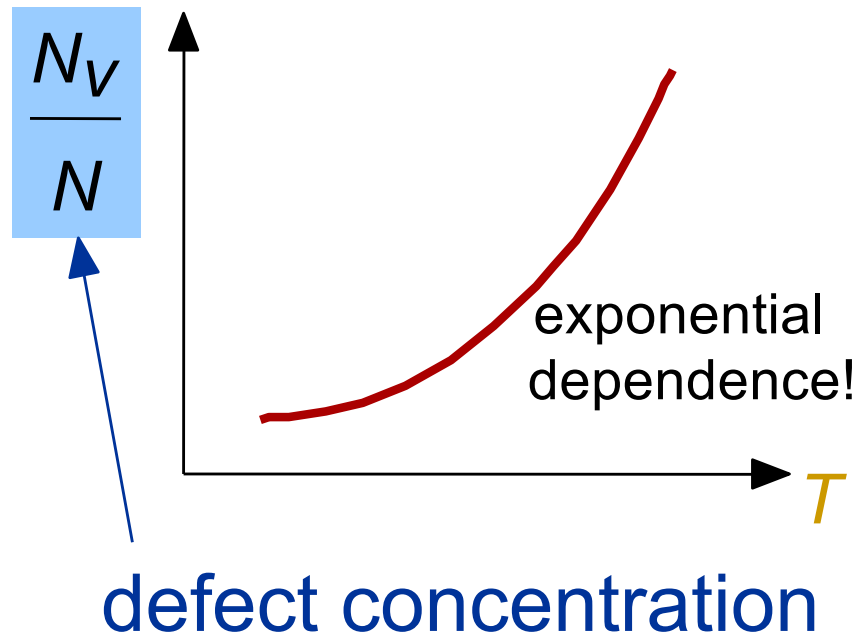
(1.38 x 10⁻²³ J/atom-K)
 (8.62 x 10⁻⁵ eV/atom-K)



Each lattice site is a potential vacancy site

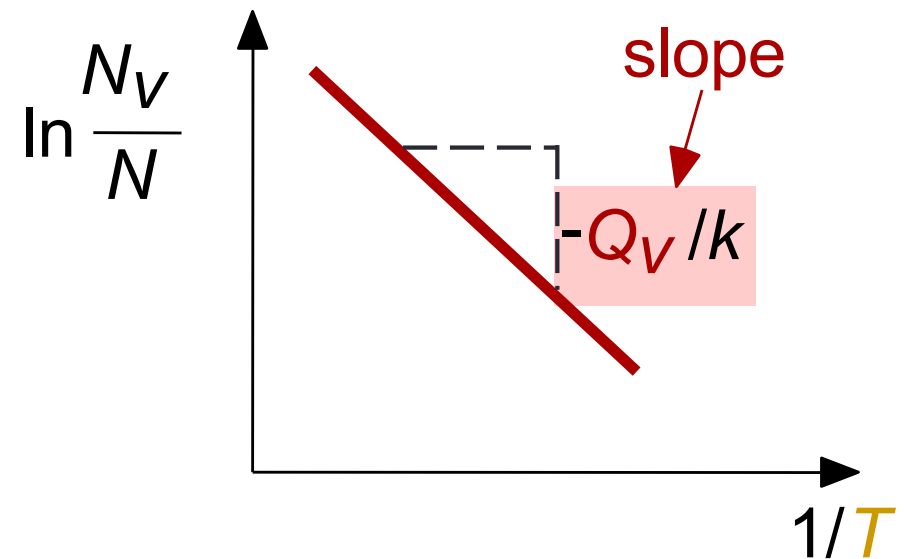
Measuring Activation Energy

- We can get Q_v from an experiment.
- Measure this...



$$\frac{N_v}{N} = \exp\left(\frac{-Q_v}{kT}\right)$$

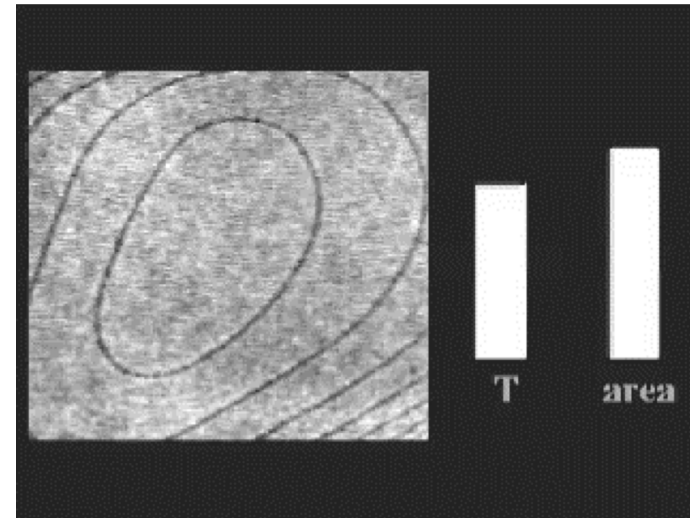
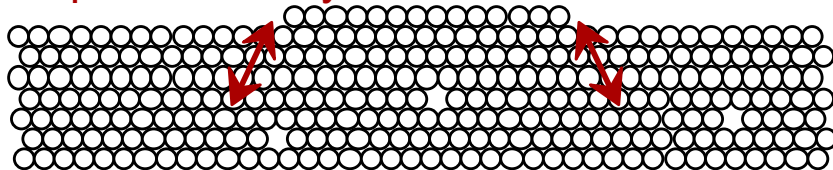
- Replot it...



Observing Equilibrium Vacancy Conc.

- Low energy electron microscope view of a (110) surface of NiAl.
- Increasing temperature causes surface island of atoms to grow.
- Why? The equil. vacancy conc. increases via atom motion from the crystal to the surface, where they join the island.

Island grows/shrinks to maintain equil. vacancy conc. in the bulk.



Reprinted with permission from Nature (K.F. McCarty, J.A. Nobel, and N.C. Bartelt, "Vacancies in Solids and the Stability of Surface Morphology", Nature, Vol. 412, pp. 622-625 (2001). Image is 5.75 mm by 5.75 mm.) Copyright (2001) Macmillan Publishers, Ltd.

Estimating Vacancy Concentration

- Find the equil. # of vacancies in 1 m³ of Cu at 1000°C.
- Given: $10^6 \text{ cm}^3 = 1 \text{ m}^3$
 $\rho = 8.4 \text{ g/cm}^3$ $A_{\text{Cu}} = 63.5 \text{ g/mol}$ (atomic weight)

$$Q_V = 0.9 \text{ eV/atom} \quad N_A = 6.022 \times 10^{23} \text{ atoms/mol}$$

$$\frac{N_V}{N} = \exp \left(\frac{-Q_V}{kT} \right) = 2.7 \times 10^{-4}$$

$Q_V = 0.9 \text{ eV/atom}$ (indicated by a red arrow)
 $kT = 1273 \text{ K}$ (indicated by a yellow arrow)
 $kT = 8.62 \times 10^{-5} \text{ eV/atom-K}$ (indicated by a green arrow)
 N_A is Avogadro's # (indicated by a black arrow)

$$\text{For } 1 \text{ m}^3, N = \rho \times \frac{N_A}{A_{\text{Cu}}} \times 1 \text{ m}^3 = 8.0 \times 10^{28} \text{ sites}$$

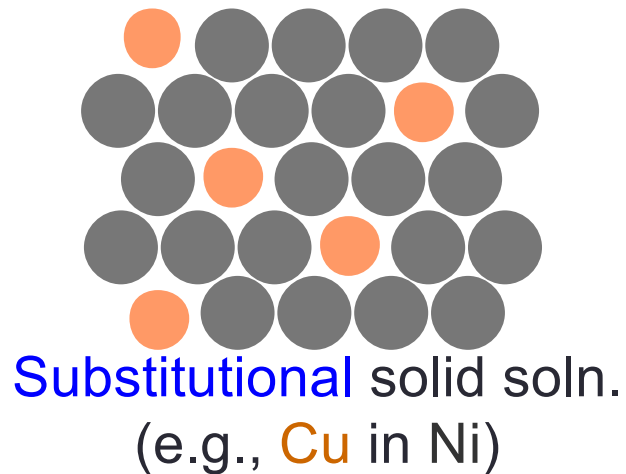
- Answer: ρ needs to be in g/m³

$$N_V = (2.7 \times 10^{-4})(8.0 \times 10^{28}) \text{ sites} = 2.2 \times 10^{25} \text{ vacancies}$$

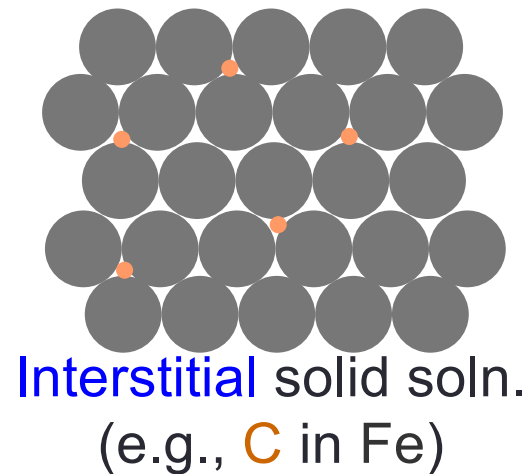
Imperfections in Metals (i)

Two outcomes if impurity (B) added to host (A):

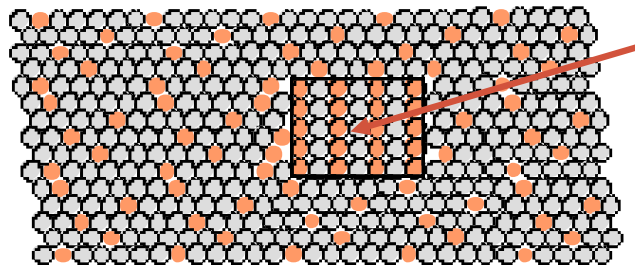
- **Solid solution** of B in A (i.e., random dist. of point defects)



OR



- Solid solution of B in A plus particles of a new phase (usually for a larger amount of B)



Second phase particle
-- different **composition**
-- often different structure.

Chapter 4: Imperfections in Solids

ISSUES TO ADDRESS...

- What are the solidification mechanisms?
- What types of defects arise in solids?
- Can the number and type of defects be varied and controlled?
- How do defects affect material properties?
- Are defects undesirable?

Imperfections in Metals (ii)

Conditions for substitutional solid solution (S.S.)

- W. Hume – Rothery rule
 - 1. Atomic size factor: Δr (atomic radius) $< 15\%$
 - 2. Same crystal structure for pure metals
 - 3. Proximity in periodic table
 - i.e., similar electronegativities
 - 4. Valency
 - All else being equal, a metal will have a greater tendency to dissolve a metal of higher valency than one of lower valency

Imperfections in Metals (ii)

- For **complete substitutional solubility**: the above criteria must be met:
 - (1) the difference in atomic radius must be less than $\pm 15\%$;
 - (2) the crystal structures must be the same;
 - (3) the valences should be the same;
 - (4) the electronegativities must be similar.

Valence & Electronegativity

(3) the valences should be the same;

- -A metal will dissolve a metal of higher valency to a greater extent than one of lower valency. The solute and solvent atoms should typically have the same valence in order to achieve maximum solubility

(4) the electronegativities must be similar.

- -Electronegativity difference close to 0 gives maximum solubility. The more electropositive one element and the more electronegative the other, the greater is the likelihood that they will form an intermetallic compound instead of a substitutional solid solution. The solute and the solvent should lie relatively close in the electrochemical series.

Imperfections in Metals (ii)

- For **incomplete substitutional solubility**: can meet only part of the criteria (less than 4 criteria)
- For **interstitial solid solution**: must meet these
 1. Impurity (solute) atom must be smaller than interstitial sites in host (solvent) lattice
 2. Similar electronegativities

Imperfections in Metals (iii)

Application of Hume–Rothery rules – Solid Solutions

- Which of the following systems (i.e., pair of metals) would you expect to exhibit complete solid solubility?

(a) *Cr (host) – V (impurity)*

<i>Metal</i>	<i>Atomic Radius (nm)</i>	<i>Crystal Structure</i>	<i>Electronegativity</i>	<i>Valence</i>
Cr(24)	0.125	BCC	1.6	+3
V(23)	0.132	BCC	1.5	+5 (+3)

(b) *Mg (host)–Zn (impurity)*

<i>Metal</i>	<i>Atomic Radius (nm)</i>	<i>Crystal Structure</i>	<i>Electronegativity</i>	<i>Valence</i>
Mg	0.160	HCP	1.3	+2
Zn	0.133	HCP	1.7	+2

Imperfections in Metals (iii)

Application of Hume–Rothery rules – Solid Solutions

- Which of the following systems (i.e., pair of metals) would you expect to exhibit complete solid solubility?

(a) Cr (host) – V (impurity)

<i>Metal</i>	<i>Atomic Radius (nm)</i>	<i>Crystal Structure</i>	<i>Electronegativity</i>	<i>Valence</i>
Cr(24)	0.125	BCC	1.6	+3
V(23)	0.132	BCC	1.5	+5 (+3)

6% difference

(b) Mg (host) – Zn (impurity)

<i>Metal</i>	<i>Atomic Radius (nm)</i>	<i>Crystal Structure</i>	<i>Electronegativity</i>	<i>Valence</i>
Mg	0.160	HCP	1.3	+2
Zn	0.133	HCP	1.7	+2

17% difference

Imperfections in Metals (iii)

Application of Hume–Rothery rules – Solid Solutions

1. Would you predict more Al or Ag to dissolve in Zn?

More Al because size is closer and val. is higher – but not too much – FCC in HCP

2. More Zn or Al in Cu?

Surely Zn since size is closer in size thus causing lower distortion (4% vs 12%)

<i>Element</i>	<i>Atomic Radius (nm)</i>	<i>Crystal Structure</i>	<i>Electro-negativity</i>	<i>Valence</i>
Cu	0.1278	FCC	1.8	+1(+2)
C	0.071			
H	0.046			
O	0.060			
Ag	0.1445	FCC	1.4	+1
Al	0.1431	FCC	1.5	+3
Co	0.1253	HCP	1.7	+2
Cr	0.1249	BCC	1.6	+3
Fe	0.1241	BCC	1.7	+2
Ni	0.1246	FCC	1.8	+2
Zn	0.1332	HCP	1.7	+2

Table on p. 135, *Callister & Rethwisch 9e*.

Interstitial Solid Solution

- Conditions: (W. Hume – Rothery rule)

1. Impurity (solute) atom must be smaller than interstitial sites in host (solvent) lattice **(MOST IMPORTANT)**

2. Similar electronegativities

Element	Atomic Radius (nm)	Δr (%)	Crystal Structure	Electro-negativity	Valence
Cu	0.1278		FCC	1.8	+1(+2)
C	0.071	-44		2.5	
H	0.046	-64		2.1	
O	0.060	-53		3.5	
Ag	0.1445	+13	FCC	1.4	+1
Al	0.1431	+12	FCC	1.5	+3
Co	0.1253	-2	HCP	1.7	+2
Cr	0.1249	-2	BCC	1.6	+3
Fe	0.1241	-3	BCC	1.7	+2
Ni	0.1246	-3	FCC	1.8	+2
Zn	0.1332	+4	HCP	1.7	+2

Impurities in Solids

- Specification of composition

- weight percent
$$C_1 = \frac{m_1}{m_1 + m_2} \times 100$$

m_1 = mass of component 1

- atom percent
$$C'_1 = \frac{n_{m1}}{n_{m1} + n_{m2}} \times 100$$

n_{m1} = number of moles of component 1